NSN 5962-01-033-5510



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-033-5510 **Body Length:** Between 0.747 inches and 0.815 inches **Body Width:** Between 0.220 inches and 0.280 inches **Body Height:** 0.200 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+200.0 degrees celsius **End Application:** Building block 57 fscm 30003 **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and high speed and wire-or outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Gold Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Precious Material And Location:** Terminals gold **Test Data Document:** 06424-10560 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:**

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N/a

6 printed circuit
Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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